

**Publisher's Note: Dependence of Carrier Doping on the Impurity Potential
in Transition-Metal-Substituted FeAs-based Superconductors
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This paper was published online on 8 March 2013 with an error in the Acknowledgments on page 4. The second sentence in the last paragraph on page 4 should read as “ARPES experiments were carried out at KEK-PF (Proposals No. 2012G075 and No. 2012S2-001).” The paper has been corrected as of 11 March 2013. The text is correct in the printed version of the journal.